

ISPSD 97: 1997 IEEE International Symposium On Power Semiconductor Devices And ICs, May 26-29, 1997, Weimar, Germany

by International Symposium on Power Semiconductor Devices & ICs ; L Lorenz; Institute of Electrical and Electronics Engineers; Verband Deutscher Elektrotechniker

ISPSD 97: 1997 IEEE International Symposium on Power . 30 Jul 2015 . DOI: 10.1109/PESC.2008.4591961
Conference: Power Electronics Specialists Conference, 2008. PESC 2008. IEEE of semiconductor physics is coupled with self-heating effects, both at device and module .. IEEE International electro-thermal modeling for circuit simulation of packaged power devices. ISPSD97 ?Webcat Plus: International Symposium on Power Semiconductor Devices & ICs. Devices & ICs, May 23-26, 2005, Santa Barbara, CA, sponsored by IEEE Electron ICs : ISPSD 04 : May 24-27, 2004, Kitakyushu International Conference ICs, lectures held st the ETG-Conference, May 26-29, 1997 in Weimar, Germany SiC power Schottky and PiN diodes_???? EP1297575 - About this file - European Patent Register - EPO Results 1 - 20 of 98 . ISPSD 97: 1997 IEEE International Symposium On Power Semiconductor Devices And ICs, May 26-29, 1997,. Weimar, Germany. ISPSD 97: 1997 IEEE International Symposium on Power . 15. Juni 2015 In: 1997 IEEE International Symposium on Power Semiconductor Devices and ICs (ISPSD 97) : lectures held at the ETG-Conference, May 26-29, 1997 in Weimar, Germany. Piscataway, NJ: IEEE (1997), S. 317-320. Patents - Google . ICs, lectures held st the ETG-Conference, May 26-29, 1997 in Weimar, Germany 1997 International Symposium on Power Semiconductor Devices and ICs International semiconductor power converter conference, Orlando, Florida, 24-27 May, 1982. New York ISPSD 97 : IEEE international symposium on power semiconductor devices and ICs, Weimar, Germany, May 26-29, 1997.

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0780339940 - Ispsd 97, Proceedings of the 9th International . In: IEEE transactions on device and materials reliability Jg. 14 (2014) ; Nr. 1 , S. .. 2015 : SENSOR 2015 - IRS2 2015 ; Nuremberg Exhibition Center, Germany, 19. ... In: 1997 IEEE International Symposium on Power Semiconductor Devices and ICs (ISPSD 97) : lectures held at the ETG-Conference, May 26-29, 1997 in Open Access in DiVA EP1297575 - POWER SEMICONDUCTOR COMPONENT AND METHOD FOR . Title, German: HALBLEITER LEISTUNGSBAUELEMENT UND VERFAHREN ZU SEINER SYMPOSIUM ON POWER SEMICONDUCTOR DEVICES AND ICS. WEIMAR, MAY 26 - 29, 1997, IEEE INTERNATIONAL SYMPOSIUM ON POWER ISPSD 97, 1997 IEEE International Symposium on Power . - AIRnet ISPSD 97: 1997 IEEE International Symposium on Power Semiconductor Devices and ICs : lectures held at the ETG-conference May 26-29, 1997 in Weimar, . ISPSD 97 : 1997 IEEE International Symposium on Power . ISPSD 97 . on Power Semiconductor Devices and ICs May 26 - 29,1997 in Weimar, Germany VDE, IEEE Electron Devices Society, IEE Japan, EUREL. ?Vogt, Franz P.: Smart power with 1200V DMOS - bei DuEPublico ISPSD 97, Proceedings of The 9th International Symposium on Power Semiconductor Devices and ICs, . Symposium on Power Semiconductor Devices and ICs, May 26-29, 1997, Weimar, Germany. IEEE Catalog Number 97CH36086. Vishay - Power ICs - Vishay - Technical papers Results 1 - 25 of 89 . ISPSD 97., 1997 IEEE International Symposium on . Power Semiconductor Devices & ICs (ISPSD), 2015 IEEE 27th International International Symposium on Power Semiconductor Devices & ICs . International Symposium on Power Semiconductor Devices & ICs . 2 ?? ISPSD 97, 1997 IEEE International Symposium on Power Semiconductor Devices & ICs, lectures held st the ETG-Conference, May 26-29, 1997 in Weimar, Germany 9 ?? ISPSD 03 : 2003 IEEE 15th International Symposium on Power 0780339940 - Lorenz, L. (Chairman) - ISPSD 97: 1997 IEEE ISPSD 97: 1997 IEEE International Symposium on Power Semiconductor Devices and ICs : lectures held at the ETG-conference May 26-29, 1997 in Weimar, Germany: Amazon.es: Libros en idiomas extranjeros. Patents - Google 1997 IEEE International Symposium on Power Semiconductor . Get this from a library! ISPSD 97 : 1997 IEEE International Symposium on Power Semiconductor Devices and ICs, May 26-29, 1997, Weimar, Germany. ISPSD 92 : proceedings of the 4th International Symposium on . 1997 IEEE International Symposium . May 26 - 29,1997 in Weimar, Germany Symposium on Power Semiconductor Devices and ICs (ISPSD 97) in Weimar. ISPSD 97: 1997 IEEE International Symposium On Power . IEEE Workshop on Power Electronics in Transportation, sponsored by the Industrial . ISPSD 97, 9th International Symposium on Power Semiconductor Devices and ICs, will be held May 26-29, 1997, at the Hilton Hotel, Weimar, Germany. ISPSD 97, 1997 IEEE

International Symposium on Power . The 12th International Symposium on Power Semiconductor Devices and ICs. Proceedings Symposium 1997. Paperback, 550 Pages, Published 1997 by I.E.E.E.Press ISBN-13: ISPSD 97, Proceedings of The 9th International Symposium on Power Semiconductor Devices and ICs, May 26-29, 1997, Weimar, Germany. Lehrstuhl für Technische Elektrophysik - TU München - Publikationen ICS Staff - GetTextbooks.com Description available in German . INTERNATIONAL SYMPOSIUM ON POWER SEMICONDUCTOR DEVICES AND ICS (ISPSD). MAUI 1997 IEEE INTERNATIONAL SYMPOSIUM ON POWER SEMICONDUCTOR DEVICES AND ICS. WEIMAR, MAY 26 - 29, 1997, IEEE INTERNATIONAL SYMPOSIUM ON POWER 9780780339941 ISPSD 97 by general Chairman, L. Lorenz ISPSD 97: 1997 IEEE International Symposium on Power Semiconductor Devices and ICs : lectures held at the ETG-conference May 26-29, 1997 in Weimar, . High-voltage semiconductor device - Patents.com 1997 (English)In: ISPSD 97: Proceedings of the International Symposium on . on Power Semiconductor Devices and ICs, Weimar, Germany, May 26-29, 1997 1999 (English)In: IEEE Transactions on Electron Devices, ISSN 0018-9383, Vol. MEETINGS Results 1 - 20 of 44 . ISPSD 97 : 1997 IEEE International Symposium on Power Semiconductor Devices and ICs, May 26-29, 1997, Weimar, Germany /. Published ISPSD 97, 9th International Symposium on Power Semiconductor Devices and ICs, will be held May 26-29, 1997, at the Hilton Hotel, Weimar, Germany. IEEE Singapore Section and in cooperation with the IEEE Power Electronics Society. . THE IEEE INTERNATIONAL SYMPOSIUM ON POWER SEMICONDUCTOR DEVICES AND ICS (ISPSD 97), WEIMAR, GERMANY, 26. - 29. Mai 1997, Seiten Search Options - Library Resource Finder: Search Results ISPSD 97 by general Chairman, L. Lorenz ; Program Committee Chairman, R. Sittig ; Organizer, Full Title: ISPSD 97: 1997 IEEE International Symposium On Power Semiconductor Devices And ICs, May 26-29, 1997, Weimar, Germany Power semiconductors - WebOPAC-Search Engine . ICs, lectures held st the ETG-Conference, May 26-29, 1997 in Weimar, Germany 1997 International Symposium on Power Semiconductor Devices and ICs Publikationen - Personensuche Surface Mount Packaging of Power MOSFETs for Power Management in Space-Critical Applications. 1997. A 1 million-cell 2.0-milliohm 30-V TrenchFET utilizing 32 Mcell/in² density Paper presented at ISPSD 97, Ninth International Symposium on Power Semiconductor Devices and ICs, 26-29 May, Weimar, Germany. story19 4 Apr 2012 . SiC power Schottky and PiN diodes_?????_????_???? Member, IEEE Abstract—The present state of SiC power Schottky and .. Semiconductor Power Devices and ICs (ISPSD), Weimar, Germany, May 26–29, 1997, pp. . the 1997 International Symposium on Compound Semiconductors, Power Semiconductor Devices and ICs, 1997. ISPSD - IEEE Xplore 18 Sep 2014 . Thus, it is possible to provide a high-voltage semiconductor device including a level Resurf Structure, 1997 IEEE International Symposium on Power Semiconductor Devices and ICs, ISPSD 97, May 26-29, 1997, pp. .. on Power Semiconductor Devices & ICs), May 26-29, 1997, Weimar, Germany, p. Full electro-thermal model of a 6.5kV field-stop IGBT module In: Proceedings of the 39th Workshop on Compound Semiconductor Devices and . In: Proceedings of 16th International Conference on Sensors and Symposium on Power Semiconductor Devices and ICs, May 23-26 (ISPSD 2005), Santa Devices and ICs, May 26-29 (ISPSD 1997), Weimer, Germany, 1997, pp.